TOSHIBA Photocoupler IRED & Photo-Transistor

TLP630

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA TLP630 consists of a photo-transistor optically coupled to two infrared emitting diode connected inverse parallel in a six lead plastic DIP package.

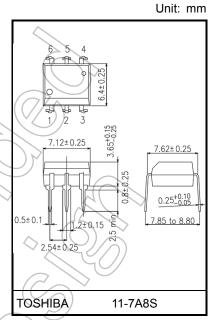
Collector-emitter voltage: 55 V (min)

• Current transfer ratio: 50% (min)

Rank GB: 100% (min)

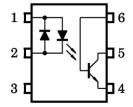
Isolation voltage: 5000 Vrms (min)

UL-recognized: UL1577, File No.E67349



Weight: 0.4 g (typ.)

Pin Configurations (top view)



1 : ANODE, CATHODE

2: CATHODE, ANODE

3 : N.C.

4 : EMITTER

5: COLLECTOR

6: BASE

Start of commercial production 1983-05

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
	Forward current	I _F (RMS)	60	mA
ED.	Forward current derating (Ta ≥ 39°C)	ΔI _F / °C	-0.7	mA / °C
	Peak forward current (100 μs pulse, 100 pps)	IFPT	±1	Α <
	Diode power dissipation	PD	100	mW
	Diode power dissipation derating (Ta ≥ 39 °C)	ΔP _D /°C	-1.2	mW/°C
	Collector-emitter voltage	V _{CEO}	55	V
	Collector-base voltage	Vсво	80	
ı	Emitter-collector voltage	VECO	7 (V
Detector	Emitter-base voltage	VEBO	7	V
De	Collector current	Ic	50	mA
	Power dissipation	Pc	150	mW
	Power dissipation derating (Ta ≥ 25°C)	ΔP _C / °C	(-1,5	mW / °C
Operating temperature range		Topr	-55 to 100	°C
Stor	rage temperature range	T _{stg}	-55 to 125	°C
Lead soldering temperature (10 s)		T _{sol}	260	•c
Junction temperature		Ţ	125	(°C)
Total package power dissipation		PT	250	(mW))
Total package power dissipation derating (Ta ≥ 25°C)		ΔP _T / °C	-2.5	mW / °C
Isolation voltage (AC, 60 s, R.H. ≤ 60 %) (Note 1)		BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: LED side pins Shorted together and DETECTOR side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	24	٧
Forward current	IF(RMS)	_	16	25	mA
Collector current	lc	_	1	10	mA
Operating temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

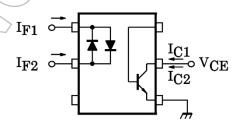
	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	I _F = 10 mA	1.0	1.15	1.3	V
E	Forward current	lF	V _F = 0.7 V	_	2.5	10	μΑ
	Capacitance	Ст	V = 0 V, f = 1 MHz	-<	60		pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5 mA	55			V
	Emitter-collector breakdown voltage	V _{(BR)ECO}	I _E = 0.1 mA	7		<u> </u>	V
	Collector-base breakdown voltage	V _(BR) CBO	I _C = 0.1 mA	80)[1	V
Detector	Emitter-base breakdown voltage	V(BR)EBO	I _E = 0.1 mA	7	<i>)</i> }_	1	V
	Collector dark current	ICEO	VCE = 24 V		10	100	nA
			V _{CE} = 24 V, Ta = 85 °C	4	2	50	μΑ
	Collector dark current	I _{CBO}	V _{CB} = 10 V)	0.1		nA
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1MHz		10	7	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	IC/IF	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$	50)	600	%
Current transfer fatto		Rank GB	100	_	600	70
Saturated CTR	lo/lec.	IF = ±1 mA, V _{CE} = 0.4 V 60	60	_	%	
Saturated CTR	IC / IF(sat)	Rank GB	30	_	_	-/0
Base photo-current	IPB	I _F = ±5 mA, V _{CB} = 5 V	//-	10	_	μА
Collector-emitter saturation	V _{CE(sat)}	IC = 2.4 mA, I _F = ±8 mA	_	_	0.4	V
voltage	OL(Sat)	10 = 11 111 1, 1,				•
Off-state collector current	IC(off)	V _F = ±0.7 V, V _{CE} = 24 V	_	1	10	μА
CTR symmetry	IC(ratio)	$I_{C}(I_{F} = -5 \text{ mA}) / I_{C}(I_{F} = +5 \text{ mA})$ (Note 1)	0.33	1	3	ı



 $I_{C(ratio)} = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 5V)}$



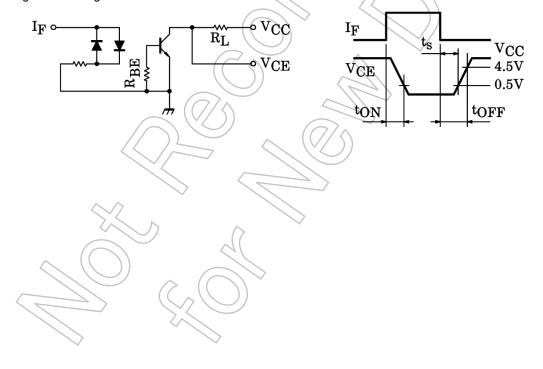
Isolation Characteristics (Ta = 25°C)

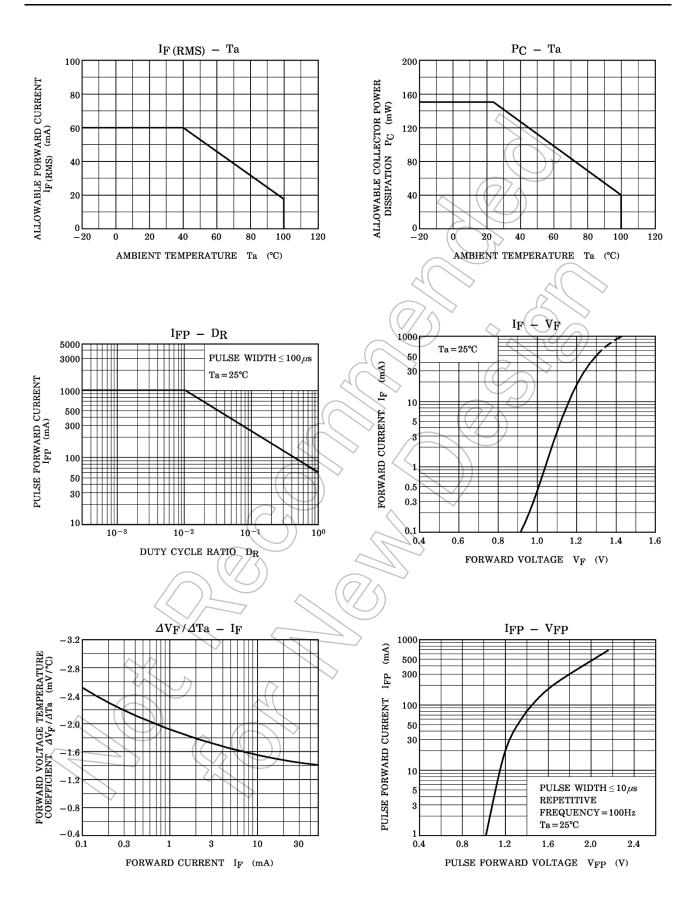
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVS	AC, 60 s	5000	/-	_	Vrms

Switching Characteristics (Ta = 25°C)

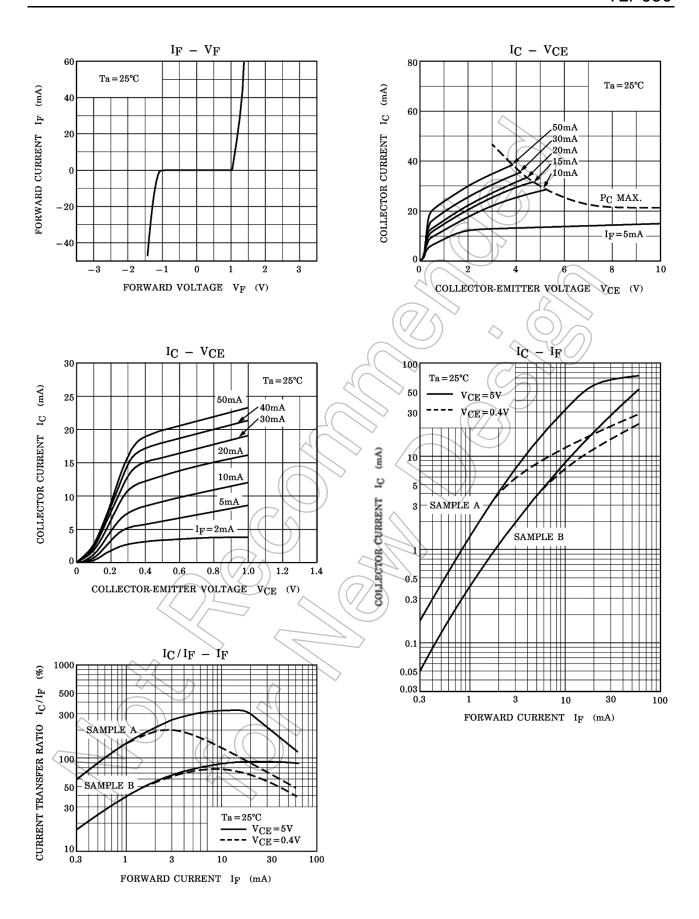
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	t _r	V _{CC} = 10V, I _C = 2mA	7/	2	_	
Fall time	t _f			3	_	
Turn-on time	toN	R _L = 100 Ω	<u> </u>	3 (μ\$
Turn-off time	toff		_	3	7	\searrow
Turn-on time	toN	$R_L = 1.9 \text{ k}\Omega$ (Fig. 1) - RBE = OPEN VCC = 5 V, $I_F = \pm 16 \text{ mA}$		2		
Storage time	ts			15	$(/\!$	μS
Turn-off time	toff		-	25		
Turn-on time	toN	$R_L = 1.9 \text{ k}\Omega$ (Fig. 1) $R_{BE} = 220 \text{ k}\Omega$, $V_{CC} = 5 \text{ V}$ $I_F = \pm 16 \text{ mA}$	+(C)	2)	_	
Storage time	ts			12	_	μS
Turn-off time	toff		(//)	20	_	

Fig. 1: Switching time test circuit

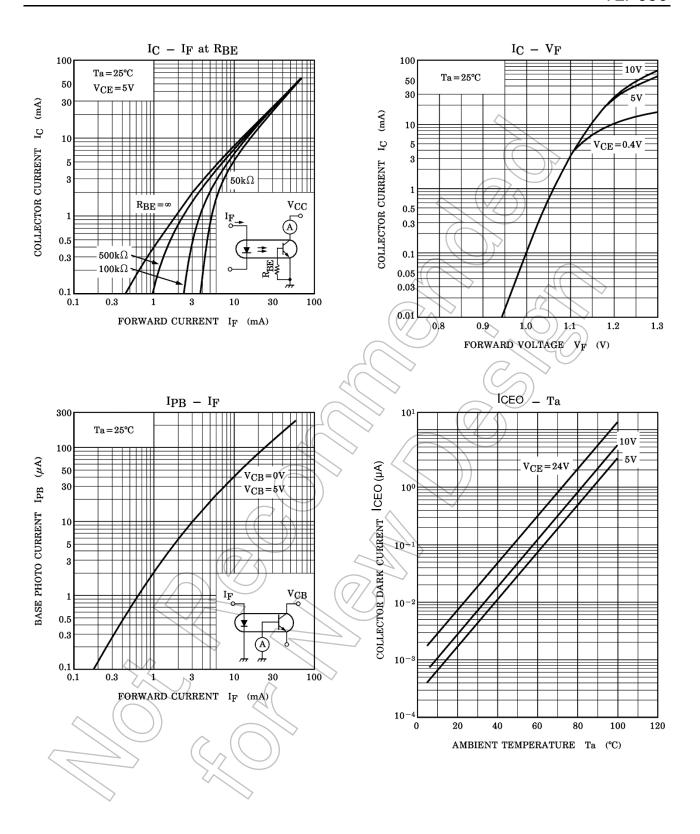




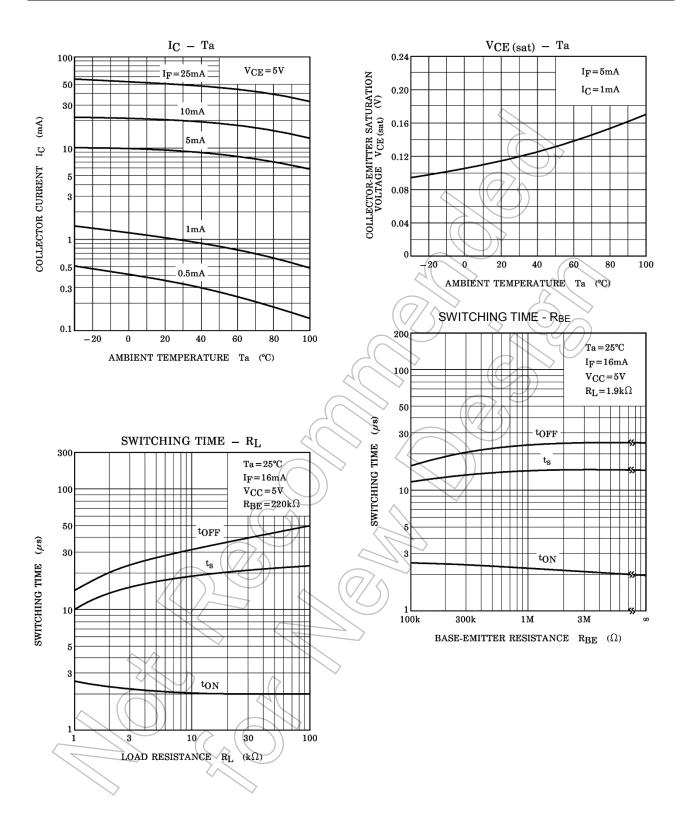
NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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